	2400 CARTON 1900	400			01251 - 1980ASOURGERS Y	16210460
First/Second	Semester	RE	Degree	Evamination	Dec.2013/Jan	201

**Basic Electronics** Time: 3 hrs. Max. Marks: 100 Note: 1. Answer any FIVE full questions, choosing at least two from each part. 2. Answer all objective type questions only on OMR sheet page 5 of the answer booklet. 3. Answer to objective type questions on sheets other than OMR will not be valued. PART - A ti. Choose the correct answers for the following: (04 Marks) The knee voltage of a silicon diode is i) A) 0.3V B) 0.5V C) 0.7V D) None of these ii) The efficiency of full waves rectifier is about A) 40.6 B) 0.46 C) 1.21 D) 81.2 The missing terms in the forward diode current is  $I_1 = I_n[e^{V/V_1} - I]$ (iii) - B) n Die C) Vs The zener diode is mainly used in A) Comparator B) Regulator C) Multivibrator D) None of these b. Discuss the behaviour of p-n junctions under: i) No bias; ii) Forward bias; iii) Reverse bias. (06 Marks) Explain the operation of full wave bridge rectifier with neat circuit diagram and waveforms. d. A zener diode has a breakdown voltage of 10V. It is supplied from a voltage source varying between 20-40V in series with resistance of 820Ω, using an ideal zener diode model obtain minimum and maximum zener currents. (04 Marks) Choose the correct answers for the following: (04 Marks) When transistor operated in cut off and saturation, it acts like A) a linear amplifier B) a switch C) a variable capacitor D) a variable resistor If the base emitter junction is open, what is the collector current ii) A) I mA B) 2mA C) 10mA D) 0 The transistor is used for impedance matching A) C-B B) C-E. C) C-C D) None of these  $\alpha$  of a transistor is 0.99 calculate  $\beta$ iv) A)  $\beta = 0.9$ B)  $\beta = 90$ C)  $\beta = 99$ D)  $\beta = 0.09$ 

b. Draw the common emitter circuit and sketch the output characteristics, explain active region, cutoff region and saturation region by indicating them on the characteristic curve. (08 Marks)

With a neat circuit diagram explain the working of transistor used as voltage amplifier.

d. For a certain transistor, 99.6% of the carriers injected into the base cross the collector-base junction. If the leakage current is 5µA and the collector current is 20mA, calculate: i) The value of a: ii) the emitter current. (04 Marks)

3	a.	Choose the correct answers for the follo	wing : (04 Marks)			
		i) The best biasing stability is achieve	[HONDON HONDON			
		A) Fixed	B) Collector to base			
		C) Voltage divider	D) None of these			
		ii) In self bias or emitter bias circuit	is connected between emitter and ground.			
		A) Inductor	B) Capacitor			
		C) Resistor	D) Zener diode			
		iii) The stability factor is given by	LY) Zieher wode			
		in) The statistics tactor is given by	ani			
		A) $\frac{dl_{CO}}{dt}$	B) dl <sub>a</sub>			
		di,	$dl_{co}$			
		$C) = \frac{dI_t}{dI_t}$	no di			
		dico	D) $\frac{dI_{co}}{dI_{co}}$			
			for the proper operation of transistor			
		<ul> <li>iv) The operating point must be</li> <li>A) High</li> </ul>	B) Stable			
		C) Increasing	D) Decreasing			
		C) increasing	(7) Decreasing			
	Ь.	With a neat circuit diagram, explain the	working of an collector-to-base bias circuit using an			
	017.43	npn transistor and derive the equation for	그림이 하면 살이 살아가면 보다 하는데 살아 있다면 하면 하면 하는데			
	535	Comments the comments districtly for a	Oleman and the bound to the bound of the			
	e.	TO ACCOMMENDATE DESCRIPTION OF A STATE OF THE PROPERTY OF THE	ilicon transistor biased by base bias method with			
		$\beta$ = 100, $R_B$ = 500K $\Omega$ , $R_C$ = 2.5K $\Omega$ and	$V_{\rm CC} = 20$ V. Also draw the load line. (06 Marks)			
	d.	Derive the stability factor S for base bia	s circuit. (04 Marks)			
2006	Marine.	Charles the second second for the Calle	m.Tourie			
*	а.	Choose the correct answers for the follo				
		<ol> <li>With gate open, if the supply volta SCR will conduct</li> </ol>	age exceeds the break over voltage of SCR, then			
		A) False	B) True			
		C) Only for D.C	D) Only for A.C			
		ii) The SCR is a device	D) Only at A.C			
		A) NPN	B) PNP			
		C) PNPN	D) PNN			
		iii) A relaxation oscillator uses	DITINI			
		A) MOSFET	B) SCR			
		C) UJT	D) BJT			
		iv) FET is a controlled device	DIBI			
		The Control of the Co	D) Compat			
		A) Voltage	B) Current			
		C) Power	D) None of these			
	b.	. Explain the construction of n-channel JFET and give its symbol.				
	c.	Write and explain the equivalent circuit	of UJT. (05 Marks)			
	d.	Explain the two transistor model of SCR	(05 Marks)			

## PART - B

5	a.	Che	pose the correct answers for the following:			(04 Marks)
		i)	Oscillator uses type of feedback			BUT (SEE SERVE)
			A) Positive	B) Negativ	ve:	
			C) Reverse	D) None o		
		(ii)	The total phase shift around a loop must be	for the	sustained oscil	llations
			A) 180°	B) 360°		
			C.) 90°	D) 270°		
		iii)	The frequency response is a graph of	800000000		
			A) frequency v, current gain	B) frequen	cy v, voltage ga	ain
			C) frequency v, output voltage	25.55	cy v, input volt	
		iv)	In RC coupled amplifier the d.c component			=
			A) Load resistance R <sub>t</sub>	B) Couplir	ng capacitor, Cc	
			C) R <sub>B</sub>	D) The tra		
	b.	With a neat circuit diagram, explain the working of a two stage capacitor				
			litier.	9.		(08 Marks)
	Ċ.	Exp	lain with the help of circuit diagram the wor	king of an	RC phase shift	oscillator usine
			sistor.			(06 Marks)
	d.	Find	the frequency of the oscillations of transisto	rized Colpit	ts oscillator hav	ing tank circuit
			meters as $C_1 = 150$ pF, $C_2 = 1.5$ nF and $L = 5$			(02 Marks)
6 a.	a.	Cho	oose the correct answers for the following:			(04 Marks)
		i)	마시 (프리카 아이트) 가게 되어 하다면서 와 아이들은 상태가 되었습니다. 경기에서 살아 되었는데 아버트 (아트리트) 함	se shift betw	een input and o	50 GMG/1004G00000000000
			A) 0°	B) 90°		
			C) 180°	D) 360°	( <b>*</b> )	
		ii)	Ideally open loop gain of op-amp is			
		154,00	A) 0	B) 1		
			C) ∞	D) Negativ	/e	
		iii)	When op-amp used as integrator with input			vill
		302	A) Ramp	B) Triangu		1077
			C) Cosine wave	D) Step		
		iv)	THE STATE OF THE S		etween sinusoi	dal sionals
			A) Phase	B) Amplitu		and a gradual
			C) Frequency	D) None o		
	b.	Write the ideal op-amp characteristics,				(06 Marks)
	c.	Shov	(06 Marks)			
	d.		w with a circuit diagram how an op-amp can b		10210200120211	
	4.	C XD3	lain how current measurement is done using C	KO.		(04 Marks)

## 10ELN15/25

7	a.	Cho	ose correct answers for the	following: (04 Marks)
		i)	Which of the following is	invalid BCD code?
			A) 0011	B) 1101
			C) 0101	D) 1001
		11)	Given the number (8BF)16	, what is the positional weight of the 8?
			A) 16	B) 256
			C) 4096	D) 8192
		iii)	$(64)_{10} - (46)_8$ in binary is	
			A) 111101101	B) 111101100
			C) 111110	D) 1100110
		iv)	172% 5%	ier power and total power in an AM wave
			A) $P_r = P_r \left( 1 + \frac{m^2}{4} \right)$	$\mathbf{B}) \ \mathbf{P}_{c} = \mathbf{P}_{\gamma} \left( 1 + \frac{\mathbf{m}^{2}}{2} \right)$
			C) $P_{\gamma} = P_{\zeta} \left( 1 + \frac{m^2}{4} \right)$	<b>D)</b> $P_1 = P_1 \left( 1 + \frac{m^2}{2} \right)$
	b. c. d.	Perfe	orm subtraction using 2's ec withe block diagram of su	f i) (225) <sub>s</sub> = (341) <sub>8</sub> ; ii) (211) <sub>s</sub> = (152) <sub>8</sub> . (06 Marks) omplement method 1101 - 1010. (04 Marks) per heterodyne receiver and explain the functions of each (06 Marks)
8	ä,	Cho	ose the correct answers for	the following : (04 Marks)
1000	3550	<b>i</b> )	De Morgan's theorem stat	(1) : [ - 1] : [ - 1
		58	A) $\overline{A} + \overline{B}$	B) A.B
		(3)	C) AB	D) A + B
		ii)		and
			A) NOT and NOR	B) AND and OR
		2000	C) NAND and NOR	D) XOR and XNOR
		iii)	For which gate when the t one?	wo inputs A and B are equal the output is zero and otherwise
			A) NAND	B) NOR
			C) EXNOR	D) EXOR
		iv)	An half adder has two inp	uts and outputs
			A) ONE	B) TWO
			C) THREE	. D) None of these
	b.	Impl	ement F.X-NOR gate using	only NOR gates. (04 Marks)
	c.	31000	olify $AB + \overline{AC} + A\overline{BC}(AB +$	
	d.	- 0	1 22	half adders and one OR gate. Write the equations for sum
	u.	and (		(06 Marks)

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